

# Corrections to “Linewidth enhancement factor measurement of silicon-based quantum dot lasers by phase modulation”

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In this paper [1], the description on page 2 is incorrectly as "According to the curve-fitting, the corner frequency  $f_c = 21.35 \text{ GHz} \gg f_m$  which means that  $\alpha_m \sim \alpha_H$  so we can use this expression to get the  $\alpha_H$ -factor. ". We would like to correct it to "According to the curve-fitting, the corner frequency  $f_c = 21.35 \text{ GHz} \gg f_m$ . Thus, the  $\alpha_H$ -factor can be get from the above expression. ".

## Reference

1. S. Ding, B. Dong, H. Huang, J. E. Bowers and F. Grillot, "The above-threshold linewidth enhancement factor of silicon-based quantum dot lasers," 2021 IEEE 17th International Conference on Group IV Photonics (GFP), 2021, pp. 1-2, doi: 10.1109/GFP51802.2021.9673822.